

Kennwerte ($T_B = 25^\circ\text{C}$)**Characteristics (cont'd)**

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Abmessungen der aktiven Chipfläche ¹⁾ Dimension of the active chip area	$L \times B$ $L \times W$	2.1×3.2	mm^2
Schaltzeiten, I_e von 10% auf 90% und von 90% auf 10%, $I_F = 1 \text{ A}$, $R_L = 50 \Omega$ Switching times, I_e from 10% to 90% and from 90% to 10%, $I_F = 1 \text{ A}$, $R_L = 50 \Omega$	t_r, t_f	10, 10	ns
Durchlassspannung Forward voltage $I_F = 1 \text{ A}, t_p = 100 \mu\text{s}$	V_F	9.5 (< 12)	V
Gesamtstrahlungsfluss Total radiant flux $I_F = 1 \text{ A}, t_p = 100 \mu\text{s}$	$\Phi_e \text{ typ}$	3.5	W
Temperaturkoeffizient von I_e bzw. Φ_e Temperature coefficient of I_e or Φ_e $I_F = 1 \text{ A}, t_p = 10 \text{ ms}$	TC_I	- 0.3	%/K
Temperaturkoeffizient von V_F Temperature coefficient of V_F $I_F = 1 \text{ A}, t_p = 10 \text{ ms}$	TC_V	- 6	mV/K
Temperaturkoeffizient von λ Temperature coefficient of λ $I_F = 1 \text{ A}, t_p = 10 \text{ ms}$	$TC_{\lambda, \text{centroid}}$	+ 0.3	nm/K

¹⁾ Die aktive Chipfläche besteht aus 6 einzelnen Chips mit je $1 \times 1 \text{ mm}^2$.The active chip area consists of 6 single chips with $1 \times 1 \text{ mm}^2$ each.

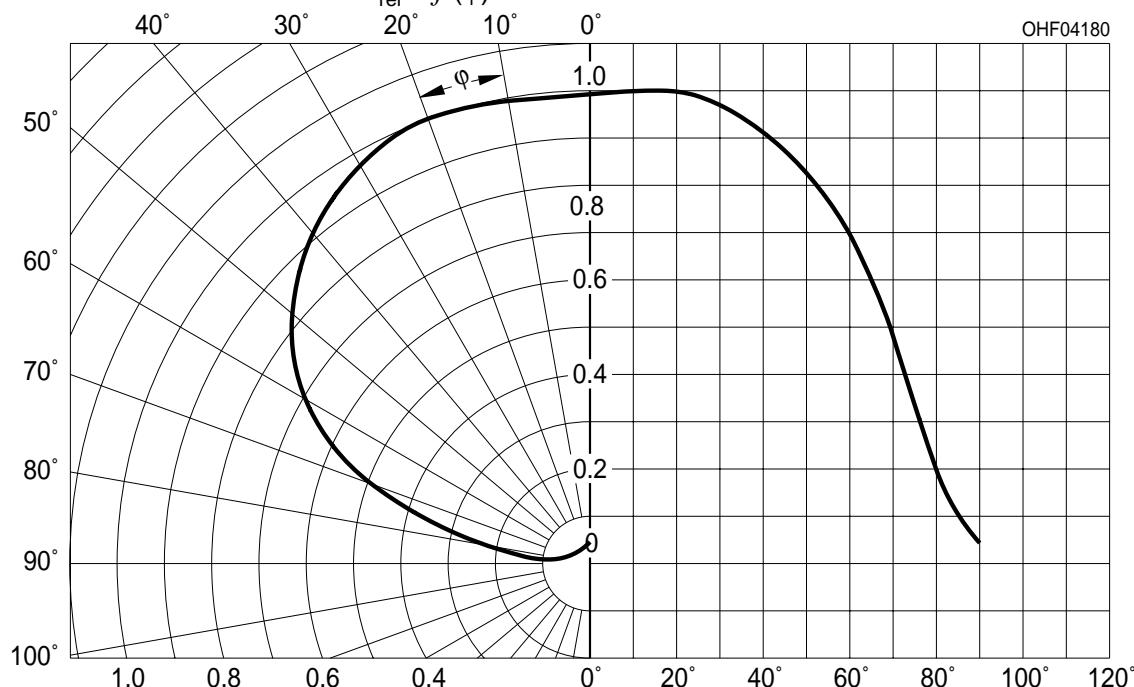
Strahlstärke¹⁾ I_e
Radiant Intensity¹⁾ I_e

Bezeichnung Parameter	Symbol	Werte Values		Einheit Unit
		SFH 4750 -EA	SFH 4750 -EB	
Strahlstärke Radiant Intensity $I_F = 1 \text{ A}$, $t_p = 20 \text{ ms}$	$I_{e \min}$ $I_{e \max}$	630 1000	800 1250	mW/sr mW/sr

¹⁾ Nur eine Gruppe in einer Verpackungseinheit (Streuung kleiner 1.6:1)
Only one group in one packing unit (variation lower 1.6:1)

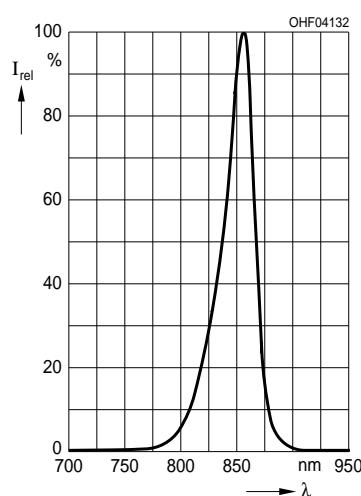
Abstrahlcharakteristik

Radiation Characteristics $I_{\text{rel}} = f(\varphi)$



**Relative spektrale Emission
Relative Spectral Emission**

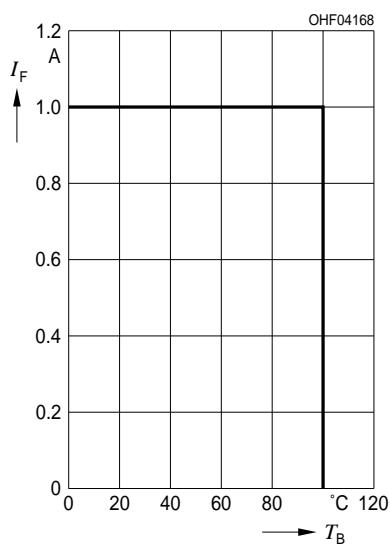
$$I_{\text{rel}} = f(\lambda), T_B = 25 \text{ }^\circ\text{C}$$



Max. zulässiger Durchlassstrom

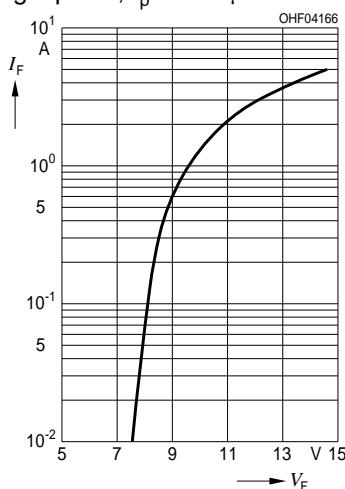
Max. Permissible Forward Current

$$I_F = f(T_B), R_{\text{thJB}} = 3 \text{ K/W}$$



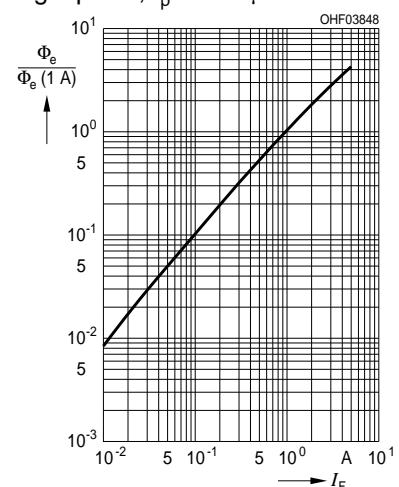
**Durchlassstrom
Forward Current**

$$I_F = f(V_F), T_B = 25 \text{ }^\circ\text{C}, \\ \text{Single pulse, } t_p = 100 \mu\text{s}$$



**Relativer Gesamtstrahlungsfluss
Relative Total Radiant Flux**

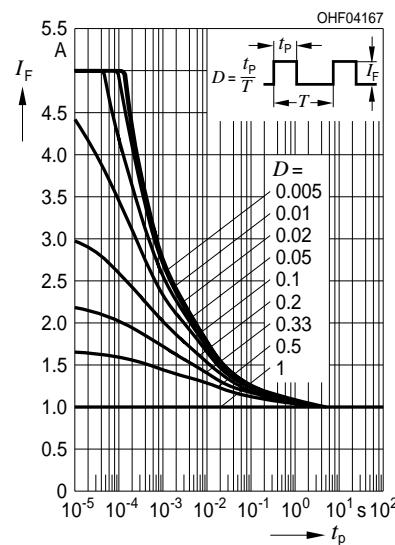
$$\Phi_e/\Phi_e(1\text{A}) = f(I_F), T_B = 25 \text{ }^\circ\text{C}, \\ \text{Single pulse, } t_p = 100 \mu\text{s}$$



Zulässige Impulsbelastbarkeit

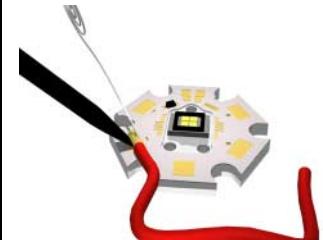
Permissible Pulse Handling

$$\text{Capability } I_F = f(t_p), T_B = 85 \text{ }^\circ\text{C}, \\ \text{Duty cycle } D = \text{parameter}$$

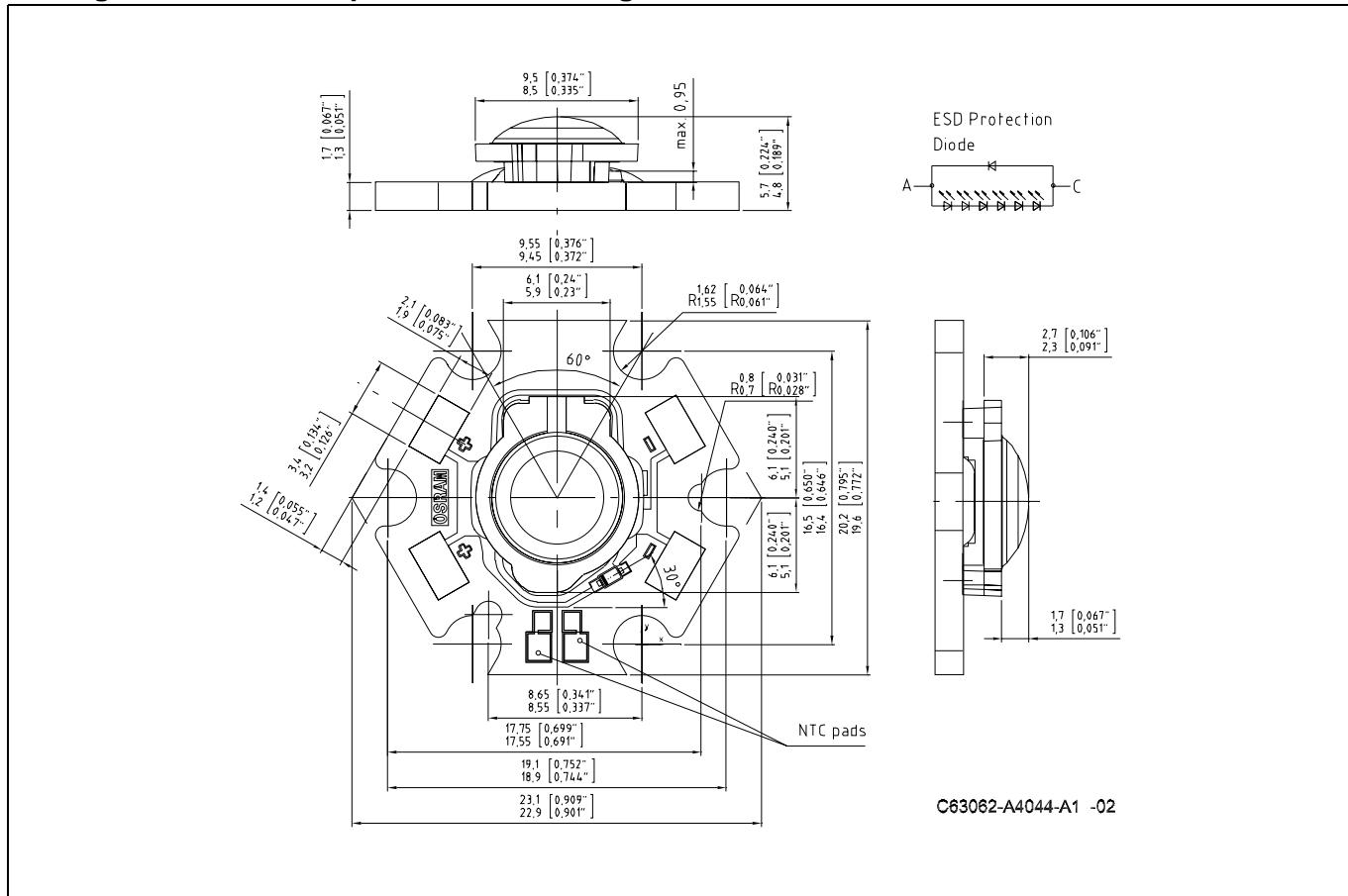


Anschlusskontaktierung Contacting

Drahttyp Wire type	Durchmesser Diameter	Lötspitze Solder Tip	Temperatur Temperature	Lötzeit Solder Time	
AWG 18	~0.8 mm (Litze; flexible wire)	3.2 mm (Meisel; Chisel)	250 °C 350 °C	16 sec. 6 sec	
AWG 20	~0.5 mm (Litze; flexible wire)	3.2 mm (Meisel; Chisel)	250 °C 350 °C	14 sec. 5 sec	
AWG 22	~0.3 mm (Litze; flexible wire)	3.2 mm (Meisel; Chisel)	250 °C 350 °C	9 sec. 3 sec	



Maßzeichnung und Ersatzschaltbild
Package Outlines and equivalent circuit diagram



C63062-A4044-A1 -02

Maße in mm (inch) / Dimensions in mm (inch).

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Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Components used in life-support devices or systems must be expressly authorized for such purpose! Critical components¹, may only be used in life-support devices or systems² with the express written approval of OSRAM OS.

¹ A critical component is a component used in a life-support device or system whose failure can reasonably be expected to cause the failure of that life-support device or system, or to affect its safety or effectiveness of that device or system.

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